

# METHOD FOR MANUFACTURING AN ELECTRON SOURCE SUBSTRATE

## BACKGROUND OF THE INVENTION

### 1. Field of the Invention

The present invention relates to a method for manufacturing an electron source substrate to be used in an electron beam device and an image forming device such as an image display device or an application of the electron beam device.

### 2. Description of the Related Art

The electron source substrate of this kind is provided with a plurality of electron emission elements constructing an electron emission portion. As the electron emission elements, there are generally known two kinds of a thermal electron source and a cold cathode electron source. This cold cathode electron source is divided into a field emission element (FE element), a metal-insulator-metal element (MIM element), a surface-conduction electron-emitting element (SCE element), and so on.

Fig. 16 is a diagram showing an element construction of M. Hartwell as a typical element construction of the surface-conduction electron-emitting element. In Fig. 16: numeral 1 designates a substrate; numerals 2 and 3 element electrodes; numeral 4 a conductive thin film; and numeral 5 an electron emission portion.

The surface-conduction electron-emitting element thus constructed has an especially simple structure of the cold cathode electron source and can be easily manufactured.

Therefore, the surface-conduction electron-emitting element has an advantage that a multiplicity of elements can be formed over a wide area.

The application of the surface-conduction electron-emitting elements has been investigated to find an image forming device such as an image display device or an image recording device, or a charge beam source.

Especially as the application to the image display device, there has been investigated an image display device, which combines the surface-conduction electron-emitting elements and a fluorescent member for emitting a light when irradiated with an electron beam, for example, as disclosed in USP 5,066,883. The image display device using the surface-conduction electron-emitting elements and the fluorescent member in combination has characteristics superior to those of the image display device of another type in the conventional art.

As compared with a liquid crystal display device spreading in recent years, for example, the above-mentioned device is superior in the points that it requires no back light because of a self luminescence type and in that the angle of view is wide. Because of the simple structure, moreover, the image display device is expected to be applied especially to the image forming device of a large area.

In the image forming device of this kind, generally speaking, there is frequently adopted the construction, in which a spacer is arranged between a rear plate having an electron source substrate and a face plate having a fluorescent member

or an anode member. The space between the rear plate and the face plate is set in vacuum so that the atmospheric pressure may be supported by the spacer having a sufficient mechanical strength thereby to keep the plate distance constant. The role of the spacer is the more important as the screen of the image forming device has the larger area.

Here, this spacer may exert influences on the orbits of electrons to fly between the rear plate and the face plate. The causes for influencing the electron orbits are the charge of the spacer. This spacer charge is thought to result from that either a portion of the electrons emitted from the electron source or the electrons reflected on the face plate come into the spacer so that secondary electrons are emitted from the spacer, or that the ions ionized by the collisions of the electrons attach to the spacer surface.

When the spacers are positively charged, the electrons flying near the spacer are attracted by the spacer so that the display image is distorted near the spacer. The influences of this charge become the more prominent as the distance between the rear plate and the face plate becomes the larger.

As the method for preventing this problem, there has been known a method for forming electron orbit correcting electrodes at the spacer or a method for removing the charges by making the charge face conductive to feed a little current.

The Applicant has been investigated the application of the technique of an ink jet device to the manufacture of the electron source substrate having the surface-conduction

electron-emitting elements. In this technique, a metal containing solution is applied in the state of liquid droplets to a substrate thereby to form a conductive thin film, and an electron emission portion is formed in the conductive thin film. At this time, an electron source substrate of a large area can be manufactured in a high throughput by applying a plurality of liquid droplets simultaneously with an ink jet device having a plurality of nozzles.

However, the following problems are left unsolved in the aforementioned manufacturing method.

The nozzles belonging to the ink jet device are not always constant in their distances. Therefore, the individual nozzles are different in the liquid droplet application position (i.e., the drop placement) of the metal containing solution. As a result, the positions of the electron emission portions to be manufactured may vary to invite a degradation of the image quality. If this variation occurs especially at such a portion of the screen, e.g., the central portion of the screen as displays important information, the degradation of the image quality is easily recognized to raise a problem as the display device. In the case of the aforementioned display device using the spacer, on the other hand, even the slight positional displacement of the electron emission portions near the spacer at the manufacturing time exerts serious influences on the electron orbits thereby to distort the display image, so that the image quality is seriously degraded.

In order to avoid these disadvantages, therefore, it is

conceivable to form the electron source substrate of a large area by using an ink jet device having an extremely high accuracy, which has little difference in the liquid droplet applying positions of the individual nozzles. In this case, however, the production yield of the ink jet device itself drops so that the cost for the electron source substrate also rises disadvantageously.

In EP869528A (corresponding to JP-A-H10-334837), moreover, the Applicant has clarified that the distortion of the display image can be eliminated by adjusting the arrangement distance of the electron emission portions near the spacer. For example, in case the conductive thin films are to be formed as a whole by the ink jet device having a plurality of nozzles, however, the positions of the electron emission portions cannot be individually controlled to make it difficult to form the electron source substrate of a high quality in a high throughput.

#### SUMMARY OF THE INVENTION

The present invention has been conceived in view of the circumstances thus far described and has an object to provide a technique for manufacturing an electron source substrate of a high quality at a low cost and in a high throughput.

An electron source substrate manufacturing method of the invention for achieving the above-specified object has been conceived by the keen investigations for solving the aforementioned problems.

Specifically, a method for manufacturing an electron

source substrate according to the invention comprises the steps of: forming a plurality of electrode pairs over the substrate; forming conductive films by applying liquid droplets containing a conductive substance between the plurality of the electrode pairs with a plurality of kinds (i.e., at least two kinds) of ink jet devices; and forming an electron emission portion in the conductive film.

Here, at the time of applying the liquid droplets, for the electrode pairs arranged at a predetermined region, there may be used the ink jet device of a kind different from that for the electrode pairs arranged at the remaining regions. In short, the kinds of the ink jet devices are properly used for the regions.

In the electron source substrate of the construction, in which the anode member can be arranged to confront through the spacer, for example, at least for the electrode pairs arranged in the vicinity of the fixed portion of the spacer, there is used the ink jet device of a kind different from that for the remaining electrode pairs.

In the electron source substrate to be used in the image display device, alternatively, at least for the electrode pairs arranged at the screen central portion, there is used the ink jet device of a kind different from that for the electrode pairs arranged at the screen end portions.

By thus making the kinds of the ink jet devices to be used different between the electrode pairs arranged at the predetermined regions or the regions required to have a high

positional accuracy and the remaining electrode pairs, it is possible to make the low cost and the high throughput compatible.

Here, the phrase "different kinds" means that the ink jet devices have different performances and specifications. For the electrode pairs arranged at the regions required to have a high positional accuracy, for example, there may be used the ink jet device, which has excellent performances in the drop placement accuracy or the drop volume accuracy. For the electrode pairs arranged near the fixed position of the spacer, for example, there may be used the ink jet device, which has a nozzle arrangement different from that for the remaining electrode pairs. Here, in order to improve the production yield of the ink jet device having the special performances and specifications at the manufacturing time, it is arbitrary to make the nozzle number less than that of the others.

The aforementioned plurality of kinds of ink jet devices may be made different of each other or may be made such that the head portions (i.e., united nozzles) of the individual ink jet devices are connected and scanned with a common control system (as will be called the "unit"). In either case, the throughput can be improved when the liquid droplets are simultaneously applied with a plurality of kinds of ink jet devices.

The invention uses the plurality of kinds of ink jet devices properly for the regions, as has been described hereinbefore, an electron source substrate of a high quality can be manufactured at a low cost and in a high throughput.

## BRIEF DESCRIPTION OF THE DRAWINGS

In the accompanying drawings:

Fig. 1 is a schematic perspective view showing an image display device as an applied example of an electron source substrate;

Fig. 2 is a schematic diagram showing an electron source substrate according to a first embodiment of the invention and an ink jet device to be used for manufacturing the electron source substrate;

Fig. 3 is a schematic diagram showing a surface-conduction electron-emitting element constructing an electron emission portion of the electron source substrate;

Fig. 4 is a schematic diagram for explaining a liquid droplet application by the ink jet device;

Fig. 5 is a schematic diagram for explaining a step of forming element electrodes;

Fig. 6 is a schematic diagram for explaining a step of forming a Y-direction wiring;

Fig. 7 is a schematic diagram for explaining a step of forming an interlayer insulating layer;

Fig. 8 is a schematic diagram for explaining a step of forming an X-direction wiring;

Figs. 9A and 9B are schematic diagrams for explaining the relative movements of an ink jet device unit and a substrate;

Fig. 10 is a schematic diagram for explaining a step of forming a conductive thin film;

Figs. 11A and 11B are explanatory diagrams illustrating



voltage waveforms at a forming step;

Figs. 12A and 12B are explanatory diagrams illustrating voltage waveforms at an activation step;

Fig. 13 is a schematic diagram showing an electron source substrate according to a second embodiment of the invention and an ink jet device to be used for manufacturing the electron source substrate;

Fig. 14 is a schematic diagram for explaining a sensitivity to a display image;

Fig. 15 is a schematic diagram showing an electron source substrate according to a third embodiment of the invention and an ink jet device to be used for manufacturing the electron source substrate; and

Fig. 16 is a diagram showing a typical element construction of a surface-conduction electron-emitting element.

#### DESCRIPTION OF THE PREFERRED EMBODIMENTS

Preferred embodiments of the invention will be exemplified in detail with reference to the accompanying drawings. The electron source substrate to be exemplified is preferred to be used either as an electron source of an image forming device such as an image display device or an image recording device or as a charged beam source.

Here, the size, material, shape and relative arrangement of the components to be described in the following embodiments are not intended to limit the scope of the invention thereto, unless otherwise specified.

(First Embodiment)

Fig. 1 is a schematic perspective view showing an image display device as an applied example of an electron source substrate according to the first embodiment of the invention.

The image display device is schematically constructed to include a rear plate 81 and a face plate 82.

The rear plate 81 is provided with an electron source substrate 80 having a plurality of electron emission portions formed therein. This electron source substrate 80 is provided with a plurality of electron emission elements 87 arrayed two-dimensionally in the X-direction and the Y-direction, and X-direction wires 88 and Y-direction wires 89 for wiring those electron emission elements 87 in a simple matrix shape. Here in Fig. 1, only 5 x 4 twenty electron emission elements 87 are shown for simplicity of explanation. As a matter of fact, however, the electron emission elements 87 are arrayed in the order of several millions to several tens millions.

The face plate 82 is constructed such that a fluorescent film 84, a metal back 85 and so on are formed on the inner face side (i.e., the electron source substrate side) of a glass substrate 83. The metal back 85 is an anode member for receiving an acceleration voltage applied from a high-voltage terminal Hv, to accelerate the electrons emitted from the electron source substrate 80. The fluorescent film 84 is an image forming member to fluoresce when it receives the irradiation of the electron beam.

The rear plate 81, a support frame 86 and the face plate

82 are adhered with frit glass and baked at 400 to 500 °C for 10 minutes or longer so that they are sealed to form an envelope 90 of the image display device. This envelope 90 has its inside set to a vacuum state.

At this time, a support member or a spacer 91 is interposed between the face plate 82 and the rear plate 81 so that the envelope 90 may have a sufficient strength against the atmospheric pressure even in the case of a panel having a large area. The spacer 91 is fixed on a predetermined X-direction wire, as shown. By thus arranging the face plate 82 to confront the electron source substrate 80 through the spacer 91, the distance between the electron emission portion and the fluorescent film 84 can be held constant all over the screen thereby to form a satisfactory image having no distortion.

Here will be detailed the construction of the aforementioned electron source substrate and its manufacturing method.

Fig. 2 is a schematic diagram showing the electron source substrate and an ink jet device to be used for manufacturing the electron source substrate. Fig. 3 is a schematic diagram showing a surface-conduction electron-emitting element constructing an electron emission portion of the electron source substrate.

The electron source substrate takes a construction, in which a plurality of surface-conduction electron-emitting elements is arrayed two-dimensionally. Each electron emission element is constructed to include: electrode pairs composed of

element electrodes 2 and 3 formed over a substrate 1; a conductive thin film 4 formed between the paired electrodes; and an electrode emission portion 5 formed in the conductive thin film 4. The element electrodes 2 of the electron emission elements arrayed in the same row of Fig. 2 are connected with the same X-direction wire 11, and the element electrodes 3 of the electron emission elements arrayed in the same column are connected with the same Y-direction wire 10.

The distance between the element electrodes 2 and 3 is preferably set to several tens nm to several hundreds  $\mu\text{m}$ . On the other hand, the voltage to be applied between the element electrodes 2 and 3 is desirably the lower, and a well reproducible manufacture is required so that the especially preferable element electrode distance is several  $\mu\text{m}$  to several tens  $\mu\text{m}$ . The length of the element electrodes 2 and 3 is preferred to be several  $\mu\text{m}$  to several hundreds  $\mu\text{m}$  from the resistance of the electrodes and electron emission characteristics. The film thickness of the element electrodes 2 and 3 is preferred to be several tens nm to several  $\mu\text{m}$ .

The conductive thin film 4 or the portion containing the electron emission portion 5 is especially preferred to be a fine particle film composed of fine particles for achieving satisfactory electron emission characteristics. The film thickness of the conductive thin film 4 is properly set to 1 nm (10 angstroms) to 50 nm (500 angstroms), preferably, according to the element electrodes 2 and 3 and the later-described energization forming conditions. On the other hand, the sheet

resistance is preferably  $10^3$  to  $10^7 \Omega/\square$ . Here, the sheet resistance is defined as the resistance, which is converted to a unit thickness (mm unit) of a conductor having equal length and width.

As shown in Fig. 4, the ink jet devices 109 and 110 are used to form the conductive thin film by discharging/applying liquid droplets 8 containing a conductive substance between the element electrodes 2 and 3, which are formed in advance over the substrate 1.

The ink jet devices 109 and 110 may be any one if they can form arbitrary liquid droplets, but are preferred to be of an ink jet system capable of controlling the drop volume (the amount of discharge) within a range of a ten and several ng to several tens ng and capable of forming liquid droplets easily in an amount as small as several tens ng or more. Moreover, the material for the liquid droplets may be any if it can form the liquid droplets, but can be exemplified by a solution prepared by dispersing or dissolving a metal or the like into water or a solvent, or a solution of an organic metal.

The ink jet forming system using the ink jet devices is specified by the following procedure.

First of all, the insulating substrate 1 is sufficiently rinsed with an organic solvent or the like and is dried. After this, a plurality of electrode pairs (i.e., the element electrodes 2 and 3) are formed over the substrate 1 by using the vacuum evaporation technique and the photolithographic technique, as shown in Fig. 5.

Next, the Y-direction wires 10 are formed to connect the element electrodes 3 arranged in the column direction (Y-direction), electrically with each other, as shown in Fig. 6.

After this, an interlayer insulating layer 6 is formed, as shown in Fig. 7. This interlayer insulating layer 6 is so formed to insulate the Y-direction wires 10 and the X-direction wires 11 to be formed at a later step as to cover the intersecting portions, at which the two wires overlap. Moreover, contact holes are formed at the connecting portions between the X-direction wires 11 and the element electrodes 2 so that they can be electrically connected.

Subsequently, the X-direction wires 11 are formed, as shown in Fig. 8, to connect the element electrodes 2 arranged in the row direction (X-direction), electrically with each other. The substrate manufactured by the foregoing steps is called the MTX substrate (matrix substrate).

For this MTX substrate, the conductive thin films are formed by using the ink jet devices 109 and 110.

In the image display device in this embodiment, the spacer 91 is arranged on a predetermined X-direction wire (as the corresponding X-direction wire is indicated by numeral 115 in Fig. 2). As described above, by the influence of charge of the spacer upon the electron emission, the electron emission elements in the vicinity of the spacer, especially the electron emission elements on the row adjacent to the spacer (as will be called the "first adjacent row") and on the row (as will be called the

"second adjacent row") next to the first adjacent row are curved in their electron orbits so that the image is easily distorted. As compared with the elements in the remaining regions, therefore, the conductive thin films of the elements arranged on the first and second adjacent rows are required to have a high positional accuracy. In other words, the electron emission elements arranged in the vicinity of the fixed position of the spacer have an extremely lower allowability for the displacement than that for the elements arranged in the remaining regions.

In this embodiment, therefore, at the time of applying the liquid droplets, at least for the element electrode pairs of the first and second adjacent rows arranged in the vicinity of the fixed position of the spacer, there is used the ink jet device of the kind different from those for the remaining element electrode pairs.

Specifically, as shown in Fig. 2, there is used an apparatus, which combines the ink jet device 109 and the ink jet devices 110, so that the conductive thin films of the first and second adjacent rows (as indicated by A in Fig. 2) may be formed by the ink jet device 109 and so that the conductive thin films of the remaining rows (as indicated by B in Fig. 2) may be formed by the ink jet devices 110.

The ink jet device 109 used here is superior in the performances such as a drop placement accuracy or a drop volume accuracy to the ink jet devices 110. Specifically, the nozzles 112 of the ink jet devices 110 are arranged in an accuracy generally matching the interval of the rows of the above-mentioned MTX

substrate, whereas the nozzles 111 of the ink jet device 109 are arranged in such a high accuracy that the conductive thin films 4 may be formed without any distortion of the image near the spacer.

The number of nozzles of the ink jet device 109 is set to such a number, e.g., four as is necessary and sufficient for forming the conductive thin films of the first and second adjacent rows as a whole. On the other hand, the ink jet device 110 has twenty nozzles (although only four nozzles are shown in Fig. 2). The nozzles 111 and 112 of the individual ink jet devices 109 and 110 are arrayed in the direction perpendicular to the spacer arranging direction.

In the used unit, moreover, the ink jet devices 110 are individually fixed on the two sides of the nozzle array direction of the ink jet device 109, and the liquid droplets of the material solution for forming the conductive thin film 4 are simultaneously injected/applied to a plurality of (i.e., forty four) electrode gaps by a plurality of (i.e., three) ink jet devices 110, 109 and 110.

At this time, the element electrode pairs of the forty four rows are treated as a whole at a high speed by applying the liquid droplets while moving the unit or the substrate relative to each other in the spacer arranging direction, as shown in Fig. 9A. Here in Figs. 9A and 9B, the hatched portion 113 indicates the region (i.e., the region where the liquid droplets are applied by the ink jet device 109) near the X-direction wire 115, in which the spacer is arranged, and the



hatched region 114 indicates the remaining region (i.e., the region where the liquid droplets are applied by the ink jet devices 110 and 110).

When the treatment of the forty four rows is ended, the position of the unit is relatively offset, as shown in Fig. 9B, for the treatment of the next element electrode pairs of the forty four rows. By repeating these operations, the liquid droplets are applied between the individual electrodes of the element electrodes pairs of the whole substrate face. After this, a heat treatment at a temperature of 300 to 600 °C is done to evaporate the solvent thereby to form the conductive thin films 4 (Fig. 10).

Subsequent to this, the electron emission portion 5 is formed in the conductive thin film 4. The electron emission portion 5 is a highly resistive crack formed in a portion of the conductive thin film 4, and is formed by the energization forming method or the like. This crack may contain conductive fine particles having a diameter of several hundreds pm to several tens nm. These conductive fine particles contain at least a partial element of the substance making the conductive thin film 4. On the other hand, the electron emission portion 5 and the conductive thin film 4 near the former may contain carbon or its compound.

The energization forming is a step of forming the electron emission portion 5 which is the portion having a modified structure, by applying an electric power between the element electrodes 2 and 3 to form the cracks in the conductive thin

film 4.

The voltage waveform to be used for the forming treatment will be briefly described. Figs. 11A and 11B are explanatory views illustrating the forming waveforms.

Here is applied a voltage of a pulse waveform. It is possible to use either of the methods properly: a method (Fig. 11A) for applying pulses having a pulse peak value at a constant voltage; and a method (Fig. 11B) for applying pulses while increasing the pulse peak value.

In Figs. 11A and 11B, characters T1 designate a pulse width of the voltage waveform, and characters T2 designate a pulse interval. In the method of Fig. 11A: the pulse width T1 is set to 1  $\mu$ secs to 10 msec; the pulse interval T2 to 10  $\mu$ secs to 100 msec; and the peak value (i.e., the peak voltage at the forming time) of the triangular waves is suitably selected. In the method of Fig. 11B, on the other hand, the magnitudes of T1 and T2 are taken similar, but the peak value (i.e., the peak voltage at the forming time) of the triangular waves is increased by steps of about 0.1 V, for example.

Here, the forming treatment is ended by inserting such a pulse voltage, e.g., about 0.1 V between the forming pulses as will neither break nor deform the conductive thin film 4, and by measuring the element current. Here, the resistance is determined from the measured element current, and the forming treatment is ended at the instant when the resistance indicates 1,000 times or more as high as that before the forming treatment, for example.

In this state, the electron emission efficiency is not so high. In order to enhance the electron emission efficiency, therefore, it is desired to subject the aforementioned elements to a treatment called the "activation".

This treatment is done by applying the pulse voltage repeatedly to the element electrodes from the outside through the X- and Y-wires under a suitable degree of vacuum, at which the organic substance exists. And, a gas containing carbon atoms is introduced to deposit the carbon or its compound derived therefrom, as a carbon film in the vicinity of the aforementioned cracks.

At the present step, p-tolunitrile is used as the carbon source and is introduced into the vacuum space through a slow leak valve so that it is kept at  $1.3 \times 10^{-4}$  Pa. The pressure of the p-tolunitrile to be introduced is slightly influenced by the shape of the vacuum device or the members used in the device but is preferred to be about  $1 \times 10^{-5}$  Pa to  $1 \times 10^{-2}$  Pa.

Figs. 12A and 12B illustrate preferable examples of the voltage application to be used at the activation step. The maximum voltage value to be applied is suitably selected within a range of 10 to 20 V.

In Fig. 12A, characters T1 designate a pulse width of the voltage waveform, and characters T2 designate a pulse interval. The positive voltage and the negative voltage are set to have an equal absolute value and an equal pulse width. In Fig. 12B, on the other hand: the characters T1 designate a pulse width of the voltage waveform of the positive voltage; characters T1'

designate a pulse width of the voltage waveform of the negative voltage; and the characters T2 designate the pulse interval. The positive voltage and the negative voltage are set to have an equal absolute value and to have a relation  $T1 > T1'$ . Either voltage application is possible.

At this time, the voltage to be applied to the element electrodes 3 is set positive, and an element current  $I_f$  is made positive when it flows from the element electrodes 3 to the element electrodes 2. At the instant when an emission current  $I_e$  reaches a substantial saturation at about 60 minutes after the voltage application, the power supply is interrupted, and the slow leak valve is closed to end the activation treatment.

According to the manufacturing method of this embodiment thus far described, the liquid droplets can be simultaneously applied between the individual electrodes of the element electrode pairs by using the ink jet devices 109 and 110, so that a high throughput can be realized.

Moreover, the ink jet device 109 of the superior performance is used for the element electrode pairs arranged in the vicinity of the fixed position of the spacer, so that the electron emission portion in the relevant region can be manufactured in the high positional accuracy. As a result, the influence from the charge of the spacer can be minimized to suppress the distortion of the displayed image.

Moreover, the ink jet device 109 of the high performance is used for the region required to have the high positional accuracy, and the ink jet devices 110 of the inferior performance

are used for the remaining regions. It is, therefore, possible to reduce the cost for the electron source substrate manufacturing apparatus and accordingly the cost for manufacturing the electron source substrate. In short, it is possible to make the low cost and the high throughput compatible. Especially in this embodiment, the number of nozzles of the superior ink jet device 109 is set to the necessary minimum so that the cost can be made lower.

Moreover, the ink jet devices 109 and 110 of the different kinds are fixed into one unit by connecting their heads to each other. It is, therefore, possible to manufacture the electron emission elements of different characteristics such as the elements required to have the positional accuracy and the elements unrequired to have the positional accuracy so much, as a whole.

Moreover, the liquid droplets are applied while the aforementioned unit and the substrate relative to each other along the spacer arranging direction. It is, therefore, possible to manufacture the electron emission elements of different characteristics in a high throughput by the remarkably simple control.

Here, in the aforementioned embodiment, the nozzle number of the ink jet device 109 is set to four. However, the nozzle number may be set to a larger value so that the liquid droplets may be applied to the regions more spaced from the spacer than the first and second adjacent rows by the superior ink jet device. By setting the nozzle number to a value less than four, on the

contrary, only the first adjacent row may be covered with the superior ink jet device.

On the other hand, the nozzle number of the ink jet device 110 should neither be limited to twenty, nor should be limited the number of combined ink jet devices to three. The throughput can be improved higher by increasing the number of nozzles and the number of ink jet devices.

(Second Embodiment)

Next, a second embodiment of the invention will be described with reference to Fig. 13.

In this embodiment, for the element electrode pairs arranged near the fixed position of the spacer, there is used an ink jet device, which has a nozzle arrangement different from that for the remaining element electrode pairs. The remaining constructions and actions are similar to those of the first embodiment so that the detail description of the similar construction portions is omitted.

As has been described, the electrons emitted from the electron emission elements on the first and second adjacent rows in the vicinity of the spacer are curved in their orbits by the influences of the spacer charge. It has been found that the curving direction approaches the spacer, and that the curvature is larger on the first adjacent row than on the second adjacent row. Considering the curvature of the electron orbits caused by the spacer charge, therefore, the positions of the electron emission elements on the first and second adjacent rows are adjusted in advance. Thus, it is possible to eliminate the

distortion of the display image.

In this embodiment, the nozzle arrangement of the ink jet device 109 to be used for the element electrode pairs (existing on the rows indicated by A in Fig. 13) arranged in the vicinity of the fixed position of the spacer is set in the following manner. Specifically, as shown in Fig. 13, the nozzle distance  $d_1$  of the two nozzles 111 and 111 at the central portion for applying the liquid droplets to the element electrode pairs of the first adjacent row and the nozzle distance  $d_2$  between the nozzle 111 for applying the liquid droplets to the element electrode pairs of the first adjacent row and the nozzle 111 for applying the liquid droplets to the element electrode pairs of the second adjacent row are set to satisfy a relation of  $d_1 > d_2$ . In other words, the nozzles 111 of the ink jet device 109 are so unequally arranged that their nozzle distances may consciously be different according to the adequate positions where the electron emission portions are formed.

On the other hand, the ink jet devices 110 used are similar to those of the first embodiment, and their nozzle distance  $d_3$  is equal (despite of a dispersion in the working accuracy). It is preferable to use the ink jet device 109 which is excellent in the drop placement accuracy and the drop volume accuracy, and it is sufficient to use the ink jet devices 110 having inferior performances.

Here: the distance  $d_1$  was set to 205  $\mu\text{m}$ ; the distance  $d_2$  to 145  $\mu\text{m}$ ; and the distance  $d_3$  to 205  $\mu\text{m}$ . With these ink jet devices 109 and 110, the conductive thin film 4 was formed as

in the first embodiment. The distance  $L_1$  between the X-direction wire 115 having the spacer arranged thereon and the center of the electron emission portion of the first adjacent row was  $170\text{ }\mu\text{m}$ , and the distance  $L_2$  between the X-direction wire adjacent to the X-direction wire 115 and the center of the electron emission portion of the second adjacent row was  $140\text{ }\mu\text{m}$ , so that the electron emission elements having the positional relation of  $L_1 > L_2$  could be formed. Here, the distance  $L_3$  was  $170\text{ }\mu\text{m}$ .

The image display device using the electron source substrate thus manufactured was driven. Both the electron beams from the electron emission portions of the first and second adjacent rows were curved in their orbits toward the spacer. As a result, the distances between the fluorescent points by the individual electron beams were substantially equalized to display an image of a high quality having no distortion.

According to the construction of this embodiment, it is possible to acquire actions and effects similar to those of the foregoing first embodiment. In addition, the ink jet device 109 having the unequal arrangement of the nozzle distances is used so that the electron emission portion in the vicinity of the spacer, as required to have the special positional relation for correcting the electron orbits, can be manufactured as a whole to realize the shortening of the manufacturing procedure and the reduction of the cost.

(Third Embodiment)

Next, a third embodiment of the invention will be described with reference to Figs. 14 and 15.



In this embodiment, for the element electrode pairs arranged at the central portion of a screen, there is used an ink jet device of a kind different from that for the element electrode pairs arranged at the end portions of the screen. The remaining constructions and actions are similar to those of the first embodiment so that the detail description of the similar construction portions is omitted.

The sensitivity to the display screen is not identical to all the spots of the screen. According to the experiments, as shown in Fig. 14, it has been found that the sensitivity of a subject is the highest at the region (i.e., at the central portion of the screen) of a narrow angle of view and becomes the lower as the spot goes the farther to the region (i.e., the end portion of the screen) of a wide angle of view. In other words, the subject cannot find it out that the screen end portion region has a poorer image quality than that of the screen central portion region.

In this embodiment, therefore, the conductive liquid droplets are applied at least to the element electrode pairs arranged at the screen central portion by using the ink jet device 109 having superior performances in the drop volume accuracy and the drop placement accuracy, as shown in Fig. 15, but the conductive liquid droplets are applied to the element electrode pairs arranged at the screen end portions by using the ink jet devices 110 having performances inferior to those of the ink jet device 109.

The three ink jet devices 110, 109 and 110 are attached

separately of each other but are so simultaneously driven as to manufacture the electron emission elements at the screen upper end portion, the screen central portion and the screen lower end portion as a whole. As a result, it is possible to realize a high throughput.

For the element electrode pairs arranged at the screen central portion, moreover, the ink jet device 109 having the excellent performances is used so that the electron emission portion of the corresponding region can be manufactured in a high positional accuracy. As a result, it is possible to improve the image quality of the region, to which the human eyes have a high sensitivity, especially.

Moreover, the electron source substrate can be manufactured without using a lot of costly ink jet devices such as the ink jet device 109, which has the high accuracy and causes the cost rise.

By manufacturing the electron emission elements for the portions required and unrequired to have the high positional accuracy, with the ink jet devices of the different kinds, moreover, many nozzles can be simultaneously used to realize the shortening of the manufacturing procedure and the lowering of the cost.

#### (Other Embodiments)

In the foregoing individual embodiments, the element electrodes and wires of the MTX substrate are manufactured by using the photolithographic technique, which may preferably be replaced by the screen printing method. The steps of forming

the remaining conductive thin film and electron emission portion are similar to those of the foregoing embodiments. As a result, the cost can be suppressed at a lower level than that for the thin film process, and the production yield is remarkably improved.

(Examples)

Here will be described in detail one preferred example of the invention, to which the invention should not be limited. Here, the description is made by using the common reference numerals with reference to the drawings used in the foregoing individual embodiments.

First of all, the insulating substrate 1 was exemplified by the glass PD-200 (made by Asahi Glass Kabushiki Gaisha) containing little alkaline component and having a thickness of 2.8 mm. A  $\text{SiO}_2$  film of 100 nm was applied to the glass and was baked as a sodium block layer. The substrate was sufficiently rinsed with an organic solvent or the like and was dried at 120 °C.

Next, a titanium Ti film of 5 nm was formed as an undercoating layer over the insulating substrate 1, and a platinum Pt film of 40 nm was formed over the former layer, by the sputtering method. After this, a photoresist was applied and was patterned by the photolithographic method having a series of exposing, developing and etching steps thereby to form the element electrodes 2 and 3 (Fig. 5). By the same method, the Y-direction wires 10 of Au were formed (Fig. 6). At this time, the element electrodes 2 and 3 has a gap distance of 20  $\mu\text{m}$ , an electrode

width of 500  $\mu\text{m}$ , a thickness of 50 nm (i.e., 500 angstroms) and an element pitch of 1 mm. The Y-direction wires 10 had a width of 300  $\mu\text{m}$  and a thickness of 50 nm (i.e., 500 angstroms).

Subsequently, in order to insulate the upper and lower wires, the vacuum filming technique and the photolithographic technique were used to arrange the interlayer insulating layer 6. The contact holes were opened at the connecting portions (Fig. 7) so as to cover the intersecting portions between the X-direction wires (i.e., the upper wires) 11 and the Y-direction wires (i.e., the lower wires) 10 and to connect the X-direction wires 11 and the element electrodes 2 electrically.

By using the vacuum filming technique and the photolithographic technique, moreover, there were formed the X-direction wires (11) of Au, which were connected with the element electrodes 2 (Fig. 8). The wires had a width of 20 nm (i.e., 200 angstroms) and a thickness of 500 nm (i.e., 5,000 angstroms).

Next, the ink jet devices 109 and 110 were used to apply an organic palladium containing solution droplet by droplet to over the element electrodes 2 and 3. The organic palladium containing solution used was prepared by dissolving a palladium-proline complex into an aqueous solution of water and isopropyl alcohol (IPA) and by adding a small quantity of additive.

At this time, the ink jet device 109 used had the four nozzles 111, and the ink jet devices 110 used had the twenty nozzles 112. Moreover, the nozzles constructing the ink jet

device 109 were so accurate that the liquid droplets discharged therefrom were  $\pm 3 \mu\text{m}$  or less with respect to a predetermined position over the MTX substrate, and the nozzles constructing the ink jet devices 110 had such a relatively low accuracy that the liquid droplets discharged therefrom were  $\pm$  about  $10 \mu\text{m}$  with respect to a predetermined position over the MTX substrate.

At the time of applying the liquid droplets, as shown in Fig. 9, the liquid droplets 8 were always applied to the region 113 near the spacer by using the ink jet device 109 and to the remaining region 114 by using the ink jet devices 110, so that the electron emission elements near the spacer were formed in the high positional accuracy.

After this, the heat treatment at  $300^\circ\text{C}$  was performed for 10 minutes to form the fine particle film of fine particles of palladium oxide (PdO) as the conductive thin film 4 (Fig. 10). One liquid droplet was controlled to  $60 \mu\text{m}^3$ .

Next, the voltage was applied between the element electrodes 2 and 3 so that the conductive thin film 4 was subjected to the energization treatment (i.e., the energization forming) to form the electron emission portion 5.

The electron source substrate thus manufactured was used to construct the envelope 90 of the face plate 82, the support frame 86, the rear plate 81 and the spacer 91, and the device was sealed to manufacture the display panel and the image forming device having the drive circuit for the TV display based on the TV signals of the NTSC system.

At this time, the position for mounting the spacer 91 was

located in the region 113, which was manufactured by the aforementioned ink jet device 109. As a result, the positions of the electron emission elements on the first and second adjacent rows in the vicinity of the spacer can be arranged in an accuracy of  $\pm 6 \mu\text{m}$ , so that the distortion of the image can be reduced to a visually unconfirmed level although the curvature of the beam due to the charge of the spacer is considered.

The electron emission elements thus manufactured by the manufacturing method of this example not only exhibited satisfactory characteristics having no problem but also could reduce the distortion of the image due to the spacer charge to a visually unconfirmed level thereby to form an image of a high quality.

By manufacturing the electron emission elements at the portions required and unrequired to have the high accuracy with the different ink jet devices, moreover, a number of nozzles could be simultaneously used, and the manufacturing procedure could be shortened and realized at a low cost.